WNSC5D20650CW

Silicon Carbide Diode

Rev.01 - 16 November 2022

Product data sheet

1. General description

Dual Silicon Carbide Schottky diode in a TO247 plastic package, designed for high frequency switched-mode power supplies.

2. Features and benefits

- Highly stable switching performance
- · Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
 Reduced cool
 - Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
 - Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			650			V
I _{O(AV)}	limiting average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 114 °C; both diodes conducting; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>		20		A	
T_{j}	junction temperature			-55 to 175		°C	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I_{F} = 10 A; T_{j} = 25 °C; per diode; <u>Fig. 5</u>		-	1.45	1.70	V
		$I_F = 10 \text{ A}; T_j = 150 \text{ °C}; \text{ per diode}; Fig. 5$		-	1.80	2.20	V
Dynamic	characteristics						
Q _r	recovered charge	I_F = 10 A; dI _F /dt = 500 A/µs; V _R = 400 V; T _j = 25 °C; per diode; <u>Fig. 7</u>		-	14.5	-	nC



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5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode		
2	K	cathode	ЩОСЦ	
3	A2	anode		к К
mb	mb	mounting base; connected to cathode		sym125

6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	name		method	quantity	version	issue date		
WNSC5D20650CW	TO247	WNSC5D20650CW6Q	Tube	30	TO247N	20-July-2016		

7. Marking

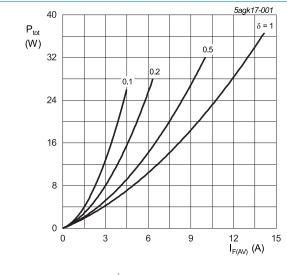
Table 4. Marking codes						
Type nu	mber	Marking codes				
WNSC5	D20650CW	WNSC5D 20650CW				

8. Limiting values

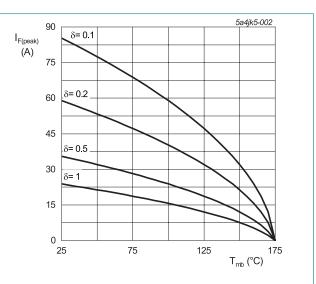
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V _{RRM}	repetitive peak reverse voltage			650	V
V_{RWM}	crest working reverse voltage			650	V
V _R	reverse voltage	DC		650	V
I _{O(AV)}	limiting average forward current	δ = 0.5; square-wave pulse; T _{mb} ≤ 114 °C; both diodes conducting; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>		20	A
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 119 °C; square-wave pulse; per diode		20	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode		60	A
		t_p = 10 µs; $T_{j(init)}$ = 25 °C; square-wave pulse; per diode		540	A
l ² t	l ² t for fusing	sine-wave pulse; $T_{j(init)}$ = 25 °C; t_p = 10 ms		18	A ² s
T _{stg}	storage temperature			-55 to 175	°C
Tj	junction temperature			-55 to 175	°C

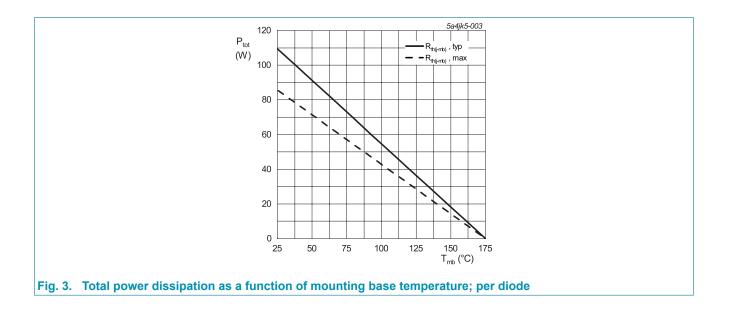


 $\begin{array}{l} I_{\text{F(AV)}} = I_{\text{F(RMS)}} \star \sqrt{\delta} \\ V_{\text{o}} = 1.103 \text{ V}; \text{ } R_{\text{s}} = 0.1048 \ \Omega \end{array} \\ \textbf{Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values; per diode} \end{array}$



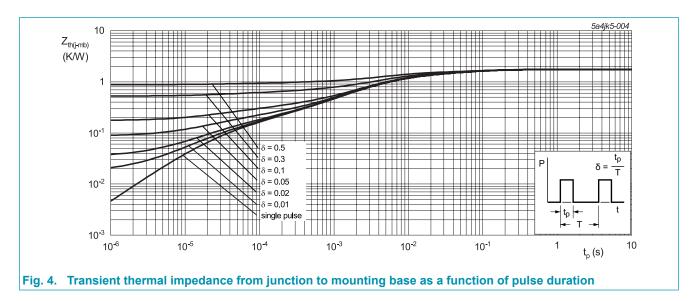


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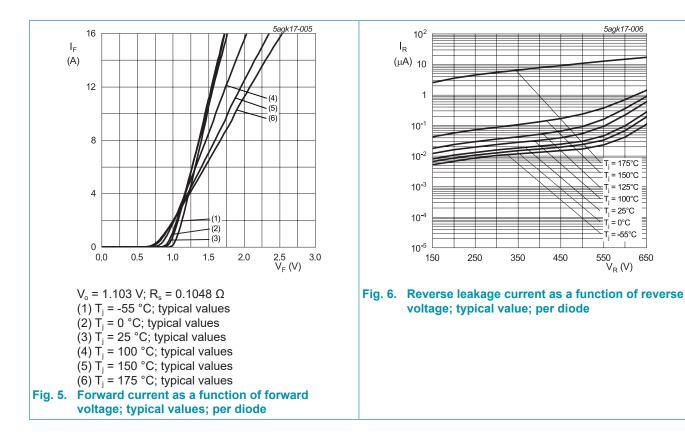
9. Thermal characteristics

Table 6. Th	ermal characteristics						
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance	per diode; <u>Fig. 4</u>		-	1.37	1.75	K/W
	from junction to mounting base	both diodes conducting		-	0.75	0.95	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W

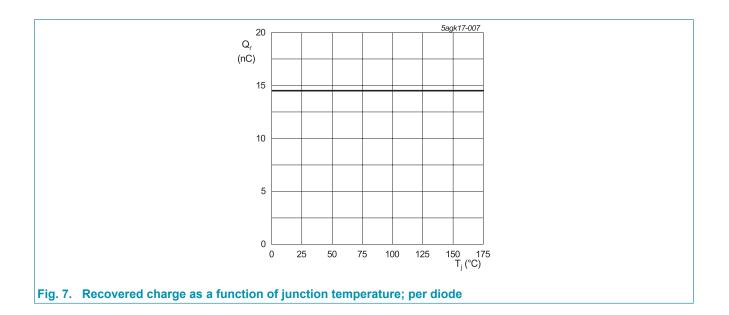


10. Characteristics

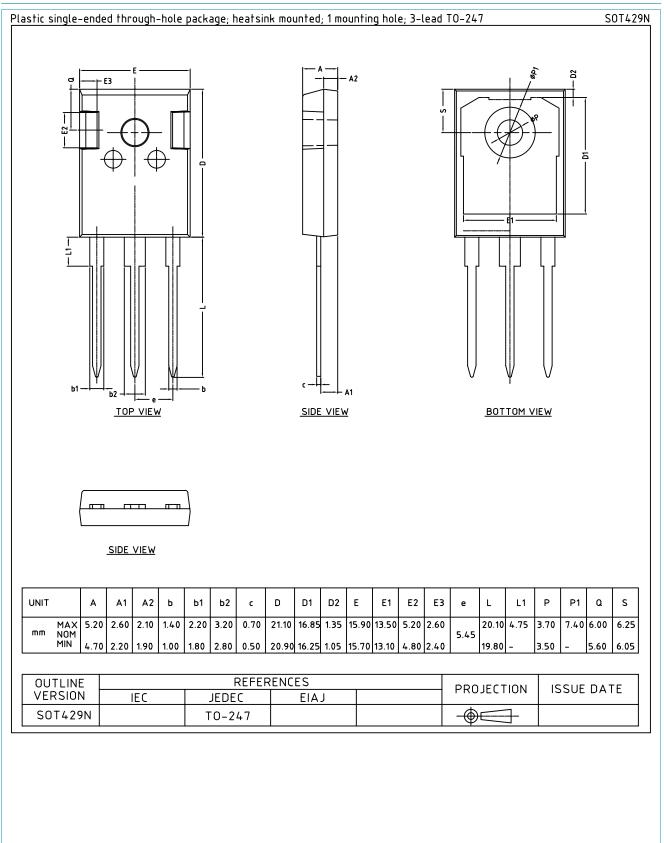
Table 7. Cl	haracteristics						
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
$V_{\rm F}$	forward current	I _F = 10 A; T _j = 25 °C; per diode; <u>Fig. 5</u>		-	1.45	1.70	V
		$I_F = 10 \text{ A}; T_j = 150 \text{ °C}; \text{ per diode}; Fig. 5$		-	1.80	2.20	V
		I _F = 10 A; T _j = 175 °C; per diode; <u>Fig. 5</u>		-	2.00	2.30	V
I _R	reverse current	V_{R} = 650 V; T_{j} = 25 °C; per diode; <u>Fig. 6</u>		-	0.5	50	μA
		V_{R} = 650 V; T _j = 175 °C; per diode; <u>Fig. 6</u>		-	25	250	μA
Dynamic	characteristics						
Q _r	recovered charge	$I_F = 10 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ per diode}; Fig. 7$		-	14.5	-	nC
C _d	diode capacitance	f = 1 MHz; V_R = 1 V; T_j = 25 °C; per diode		-	328	-	pF
		f = 1 MHz; V_R = 300 V; T_j = 25 °C; per diode		-	39	-	pF
		f = 1 MHz; V_R = 600 V; T_j = 25 °C; per diode		-	36	-	pF
E _{as}	non-repetitive avalanche energy	I_R = 4.9 A; L = 5 mH; $T_{j(init)}$ = 25 °C; per diode		60	-	-	mJ



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11. Package outline



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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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